SCR, 12 A, 15 mA, 500 V, SOT78 Rev. 01 — 18 May 2009

Product data sheet

Product profile 1.

1.1 General description

Planar passivated SCR (Silicon Controlled Rectifier) in a SOT78 plastic package

1.2 Features and benefits

- High reliability
- High surge capability

1.3 Applications

- Ignition circuits
- Motor control

Protection circuits

Static switching

High thermal cycling performance

1.4 Quick reference data

Table 1.	Quick reference					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	-	500	V
V _{RRM}	repetitive peak reverse voltage		-	-	500	V
I _{T(AV)}	average on-state current	half sine wave; T _{mb} = 133 °C; see <u>Figure 3</u>	-	-	8	А
I _{T(RMS)}	RMS on-state current	half sine wave; all conduction angles; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	-	12.5	A
I _{TSM}	non-repetitive peak on-state current	half sine wave; $t_p = 8.3 \text{ ms}$; $T_{j(init)} = 25 \text{ °C}$	-	-	132	А
		half sine wave; $t_p = 10$ ms; $T_{j(init)} = 25$ °C; see <u>Figure 4</u> ; see <u>Figure 5</u>	-	-	120	A
Static ch	aracteristics					
I _{GT}	gate trigger current	V _D = 12 V; T _j = 25 °C; I _T = 100 mA; see <u>Figure 8</u>	-	2	15	mA



Table 4 Outlak raf

2. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode		
2	А	anode	mb	А Н К
3	G	gate		G sym037
	A	mounting base; connected to anode		
			SOT78	

(TO-220AB; SC-46)

3. Ordering information

Table 3. Ordering information

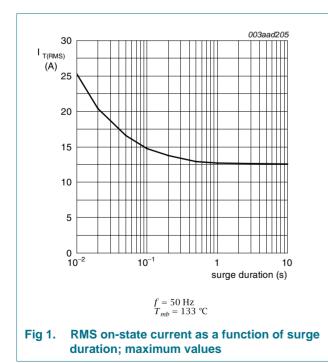
Type number	Package		
	Name	Description	Version
BT151-500RT	TO-220AB; SC-46	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78

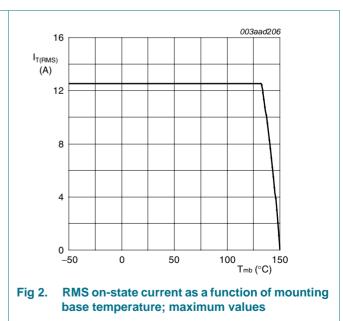
4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

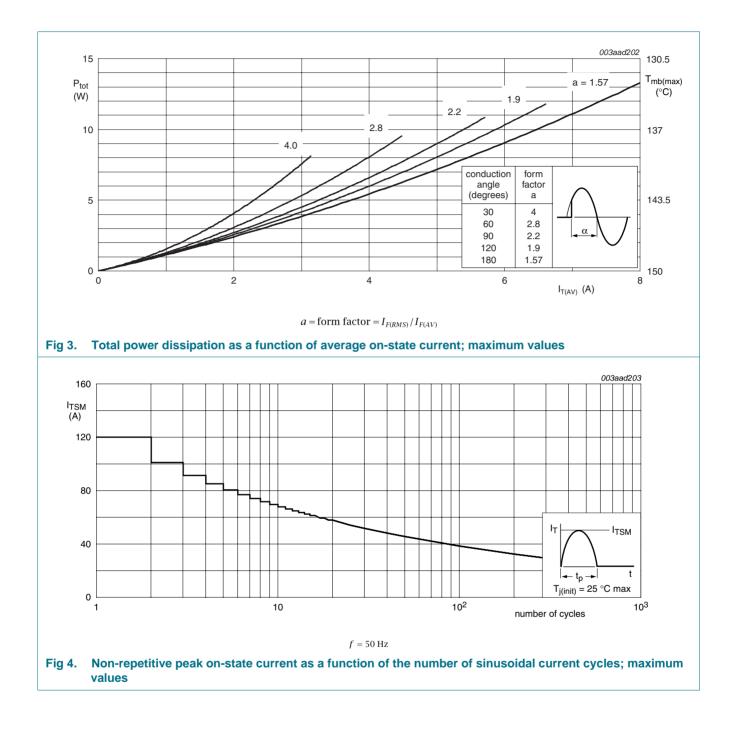
Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	500	V
V _{RRM}	repetitive peak reverse voltage		-	500	V
I _{T(AV)}	average on-state current	half sine wave; T_{mb} = 133 °C; see <u>Figure 3</u>	-	8	А
I _{T(RMS)}	RMS on-state current	half sine wave; all conduction angles; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	12.5	А
dl _T /dt	rate of rise of on-state current	I_T = 20 A; I_G = 50 mA; dI_G/dt = 50 mA/µs	-	50	A/µs
I _{GM}	peak gate current		-	4	А
P _{GM}	peak gate power		-	5	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C
I _{TSM}	non-repetitive peak	half sine wave; $t_p = 8.3 \text{ ms}$; $T_{j(init)} = 25 \text{ °C}$	-	132	А
	on-state current	half sine wave; $t_p = 10 \text{ ms}$; $T_{j(init)} = 25 \text{ °C}$; see <u>Figure 4</u> ; see <u>Figure 5</u>	-	120	А
l ² t	I ² t for fusing	t _p = 10 ms; sin-wave pulse	-	72	A ² s
P _{G(AV)}	average gate power	over any 20 ms period	-	1	W
V _{RGM}	peak reverse gate voltage		-	5	V



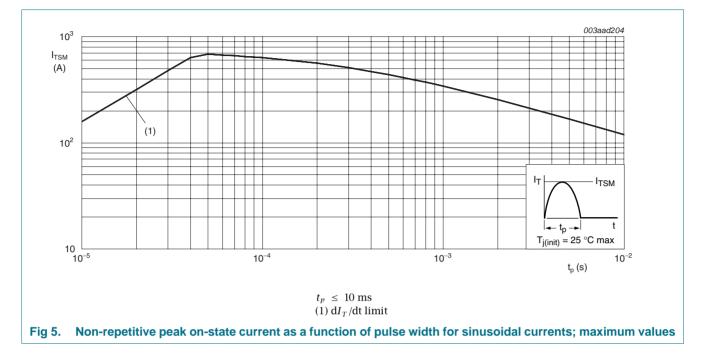


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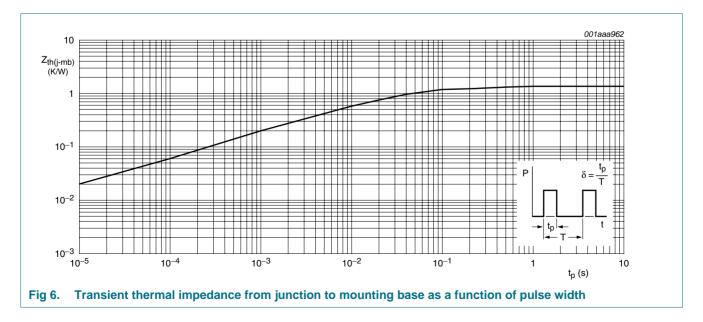
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5. Thermal characteristics

Table 5. Thermal characteristics

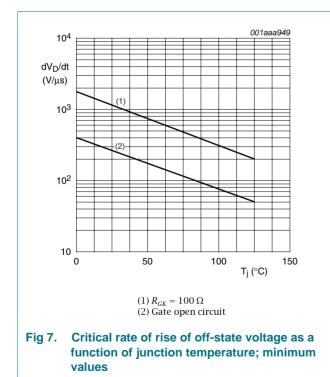
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	see <u>Figure 6</u>	-	-	1.3	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air		-	60	-	K/W



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6. Characteristics

Table 6.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Dynamic	charateristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 335 V; T _j = 125 °C; gate open circuit; see Figure 7	50	130	-	V/µs
		V_{DM} = 335 V; T_{j} = 125 °C; R_{GK} = 100 Ω	200	1000	-	V/µs
t _{gt}	gate-controlled turn-on time	$I_{TM} = 40 \text{ A}; \text{ V}_{\text{D}} = 500 \text{ V}; \text{ I}_{\text{G}} = 100 \text{ mA}; \\ \text{d}_{\text{G}}/\text{d}t = 5 \text{ A}/\mu\text{s}$	-	2	-	μs
t _q	commutated turn-off time		-	70	-	μs
Static cha	aracteristics					
I _{GT}	gate trigger current	V _D = 12 V; T _j = 25 °C; I _T = 100 mA; see <u>Figure 8</u>	-	2	15	mA
IL	latching current	V _D = 12 V; T _j = 25 °C; I _G = 100 mA; see <u>Figure 9</u>	-	10	40	mA
I _H	holding current	T _j = 25 °C; see <u>Figure 10</u>	-	7	20	mA
V _T	on-state voltage	I _T = 23 A; T _j = 25 °C; see <u>Figure 11</u>	-	1.4	1.75	V
V _{GT}	gate trigger voltage	$I_T = 100 \text{ mA}; V_D = 12 \text{ V}; T_j = 25 \text{ °C};$ see <u>Figure 12</u>	-	0.6	1.5	V
		$I_T = 100 \text{ mA}; V_D = 500 \text{ V}; T_j = 125 \text{ °C}$	0.25	0.4	-	V
I _D	off-state current	V _D = 500 V; T _j = 125 °C	-	0.1	0.5	mA
I _R	reverse current	V _R = 500 V; T _j = 125 °C	-	0.1	0.5	mA



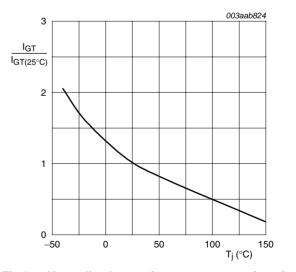
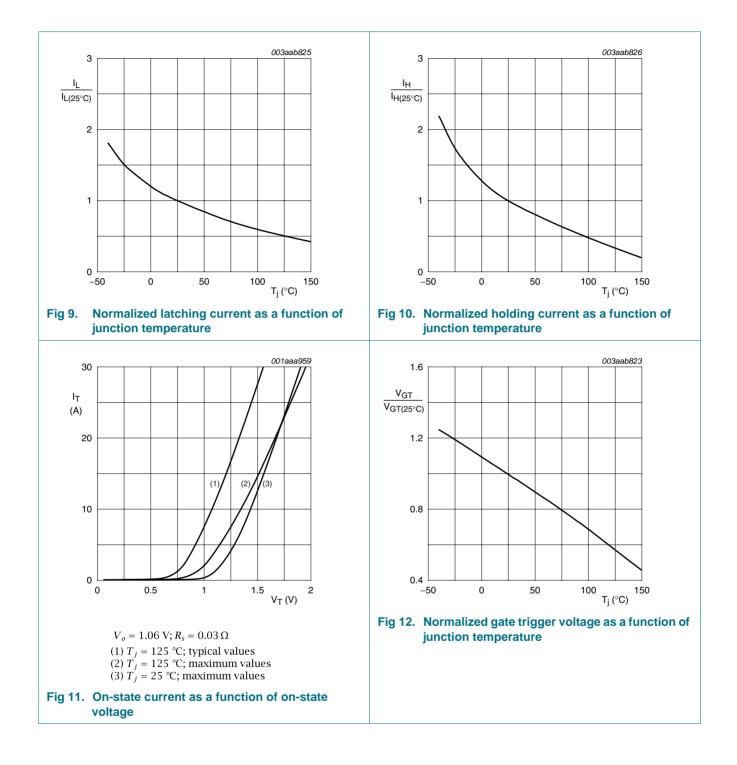


Fig 8. Normalized gate trigger current as a function of junction temperature

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7. Package outline

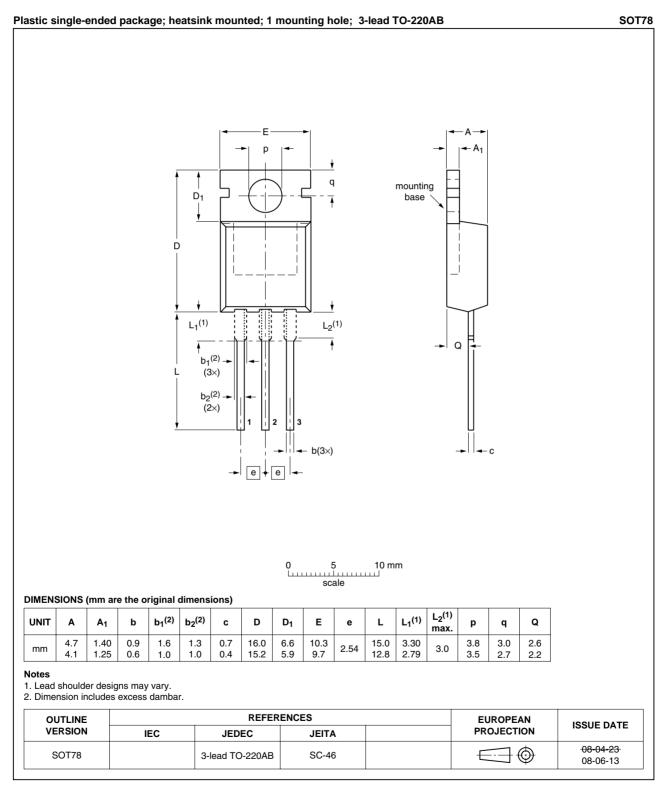


Fig 13. Package outline SOT78 (TO-220AB)

8. Revision history

Table 7. Revision hist	Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes	
BT151-500RT_1	20090518	Product data sheet	-	-	

9. Legal information

9.1 Data sheet status

Document status [1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions"

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Date of release: 18 May 2009 Document identifier: BT151-500RT_1

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